

SLOS437J-APRIL 2004-REVISED JULY 2005

### **FEATURES**

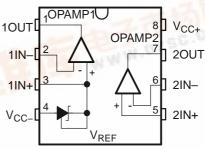
- **OPERATIONAL AMPLIFIER** 
  - Low Offset Voltage Max of:
    - TL103WA...3 mV (25°C) and 5 mV (Full Temperature)
    - TL103W...4 mV (25°C) and 5 mV (Full Temperature)
  - Low Supply Current...350 μA/Channel (Typ)
  - Unity Gain Bandwidth...0.9 MHz (Typ)
  - Input Common-Mode Range Includes GND
  - Large Output-Voltage Swing... 0 V to V<sub>CC</sub> - 1.5 V
  - Wide Supply-Voltage Range...3 V to 32 V
  - 2-kV ESD Protection (HBM)
- **VOLTAGE REFERENCE** 
  - Fixed 2.5-V Reference
  - Tight Tolerance Max of:
    - TL103WA...0.4% (25°C) and 0.8% (Full Temperature)
    - TL103W . . . 0.7% (25°C) and 1.4% (Full Temperature)
  - Low Temperature Drift...7 mV (Typ) Over **Operating Temperature Range**
  - Wide Sink-Current Range . . . 0.5 mA (Typ) to 100 mA
  - Output Impedance...0.2  $\Omega$  (Typ)

### TYPICAL APPLICATIONS

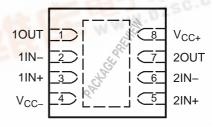
- **Battery Chargers**
- Linear Voltage Regulation

  Data-Acquisition

## D (SOIC) PACKAGE (TOP VIEW)



### DRJ (QFN) PACKAGE (TOP VIEW)



NOTE: Exposed thermal pad is connected internally to V<sub>CC</sub> via die attach.

# **DESCRIPTION/ORDERING INFORMATION**

The TL103W and TL103WA combine the building blocks of a dual operational amplifier and a fixed voltage reference – both of which often are used in the control circuitry of both switch-mode and linear power supplies. OPAMP1 has its noninverting input internally tied to a fixed 2.5-V reference, while OPAMP2 is independent, with both inputs uncommitted.

For the A grade, especially tight voltage regulation can be achieved through low offset voltages for both operational amplifiers (typically 0.5 mV) and tight tolerances for the voltage reference (0.4% at 25°C and 0.8% over operating temperature range).

The TL103W and TL103WA are characterized for operation from -40°C to 105°C.

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### **ORDERING INFORMATION**

TA	MAX V <sub>IO</sub> AND V <sub>REF</sub> TOLERANCE (25°C)	PACKAGE <sup>(1)</sup>		PACKAGE <sup>(1)</sup> ORDERABLE PART NUMBER	
	A grade 3 mV, 0.4%	QFN (DRJ)	Reel of 1000	TL103WAIDRJR	PREVIEW
		SOIC (D)	Tube of 75	TL103WAID	7402000
40°C to 405°C			Reel of 2500	TL103WAIDR	Z103WQ
–40°C to 105°C		QFN (DRJ)	Reel of 1000	TL103WIDRJR	PREVIEW
	Standard grade 4 mV, 0.7%	SOIC (D)	Tube of 75	TL103WID	Z103W
		3010 (D)	Reel of 2500	TL103WIDR	Z103VV

<sup>(1)</sup> Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

### **Typical Application Circuit**

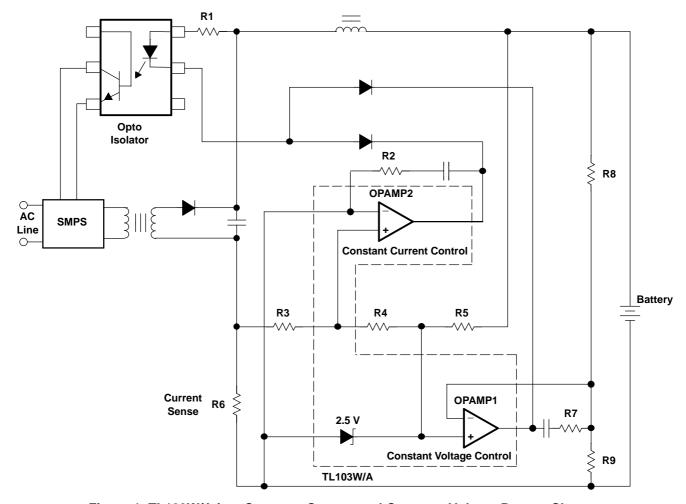


Figure 1. TL103W/A in a Constant-Current and Constant-Voltage Battery Charger



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# **Absolute Maximum Ratings**(1)

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
$V_{CC}$	Supply voltage			36	V
V <sub>id</sub>	Operational amplifier input differential voltage			36	V
$V_{I}$	Operational amplifier input voltage range		-0.3	36	V
I <sub>KA</sub>	Voltage reference cathode current			100	mA
0	Park and the sound in a state of	D package <sup>(2)(3)</sup>		97	00/11/
$\theta_{JA}$	JA Package thermal impedance	DRJ package <sup>(2)(4)</sup>		TBD	°C/W
TJ	Maximum junction temperature			150	°C
T <sub>stg</sub>	Storage temperature range		-65	150	°C

- (1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability Maximum power dissipation is a function of  $T_J(max)$ ,  $\theta_{JA}$ , and  $T_A$ . The maximum allowable power dissipation at any allowable ambient
- temperature is  $P_D = (T_J(max) T_A)/\theta_{JA}$ . Selecting the maximum of 150°C can affect reliability.
- The package thermal impedance is calculated in accordance with JESD 51-7.
- (4) The package thermal impedance is calculated in accordance with JESD 51-5.

### **Recommended Operating Conditions**

over operating free-air temperature range (unless otherwise noted)

		MIN	MAX	UNIT
$V_{IN}$	Supply voltage	3	32	V
$I_{K}$	Cathode current	1	100	mA
$T_A$	Operating free-air temperature	-40	105	°C



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# OPAMP1, Operational Amplifier With Noninverting Input Connected to the Internal $\mathbf{V}_{\text{REF}}$ Electrical Characteristics

 $V_{CC+} = 5 \text{ V}, V_{CC} = \text{GND}, T_A = 25^{\circ}\text{C} \text{ (unless otherwise noted)}$ 

	PARAMETER		TEST CONDITIONS	T <sub>A</sub>	MIN	TYP	MAX	UNIT	
		TI 102\\/	V 0.V	25°C		1	4		
V	Innut offeet valtage	TL103W	$V_{icm} = 0 V$	Full range			5	m\/	
$V_{IO}$	Input offset voltage	TI 400\\/	V 0.V	25°C		0.5	3	mV	
		TL103WA	$V_{icm} = 0 V$	Full range			5		
$\alpha V_{IO}$	Input offset-voltage dr	ift		25°C		7		μV/°C	
I <sub>IB</sub>	Input bias current (ne	gative input)		25°C		20		nA	
$A_{VD}$	Large-signal voltage of	gain	$V_{CC+} = 15 \text{ V}, R_L = 2 \text{ k}\Omega, V_{icm} = 0 \text{ V}$	25°C		100		V/mV	
k <sub>SVR</sub>	Supply-voltage rejecti	on ratio	$V_{CC+} = 5 \text{ V to } 30 \text{ V}, V_{icm} = 0 \text{ V}$	25°C	65	100		dB	
I <sub>source</sub>	Output source current		V <sub>CC+</sub> = 15 V, V <sub>O</sub> = 2 V, V <sub>id</sub> = 1 V	25°C	20	40		mA	
I <sub>SC</sub>	Short circuit to GND		V <sub>CC+</sub> = 15 V	25°C		40	60	mA	
L Output sink surrent		$V_{CC+} = 15 \text{ V}, V_{O} = 2 \text{ V}, V_{id} = -1 \text{ V}$	25°C	10	12		mA		
I <sub>sink</sub>	output sink current		$V_{CC+} = 15 \text{ V}, V_{O} = 0.2 \text{ V}, V_{id} = -1 \text{ V}$	25 C	12	50		μΑ	
			$V_{CC} = 30 \text{ V}, R_1 = 2 \text{ k}\Omega$	25°C	26	27			
V	High-level output volta	200	$V_{CC} = 50 \text{ V}, \text{ K}_L = 2 \text{ K}_{22}$	Full range	26			V	
V <sub>OH</sub>	riigii-ievei output voita	age	$V_{CC} = 30 \text{ V}, R_1 = 10 \text{ k}\Omega$	25°C	27	28		V	
			$V_{CC} = 50 \text{ V}, \text{ K}_{L} = 10 \text{ K}_{22}$	Full range	27				
V	Low lovel output volta	<b>~</b>	B = 10 kO	25°C		5	20	mV	
$V_{OL}$	Low-level output volta	ge	$R_L = 10 \text{ k}\Omega$	Full range			20	IIIV	
SR	Slew rate at unity gair	1	$V_{CC+} = 15 \text{ V}, C_L = 100 \text{ pF},$ $R_L = 2 \text{ k}\Omega, V_I = 0.5 \text{ V} \text{ to 2 V}, \text{ unity gain}$	25°C	0.2	0.4		V/μs	
GBW	Gain bandwidth produ	ıct	$V_{CC+} = 30 \text{ V}, V_I = 10 \text{ mV}, \\ C_L = 100 \text{ pF}, R_L = 2 \text{ k}\Omega, f = 100 \text{ kHz}$	25°C	0.5	0.9		MHz	
THD	Total harmonic distort	ion	$V_{CC+} = 30 \text{ V}, V_O = 2 \text{ V}_{pp}, C_L = 100 \text{ pF},$ $R_L = 2 \text{ k}\Omega, f = 1 \text{ kHz}, A_V = 20 \text{ dB}$	25°C		0.02		%	



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# **OPAMP2**, Independent Operational Amplifier Electrical Characteristics

 $V_{CC+}$  = 5 V,  $V_{CC}$  = GND,  $V_{O}$  = 1.4 V,  $T_{A}$  = 25°C (unless otherwise noted)

	PARAMETER		TEST CONDITIONS	T <sub>A</sub>	MIN	TYP	MAX	UNIT
		TI 102\\/	V 0.V	25°C		1	4	
.,	land offert values	TL103W	$V_{icm} = 0 V$	Full range			5	\/
$V_{IO}$	Input offset voltage	TI 400\\\	V 0V	25°C		0.5	3	mV
		TL103WA	$V_{icm} = 0 V$	Full range			5	
$\alpha V_{IO}$	Input offset voltage d	rift		25°C		7		μV/°C
				25°C		2	75	
I <sub>IO</sub>	Input offset current			Full range			150	nA
				25°C		20	150	
I <sub>IB</sub>	Input bias current	urrent		Full range			200	nA
			$V_{CC+} = 15 \text{ V}, R_L = 2 \text{ k}\Omega,$	25°C	50	100		.,, .,
$A_{VD}$	Large-signal voltage	gain	V <sub>O</sub> = 1.4 V to 11.4 V	Full range	25			V/mV
k <sub>SVR</sub>	Supply-voltage reject	ion ratio	V <sub>CC+</sub> = 5 V to 30 V	25°C	65	100		dB
				25°C	0		V <sub>CC+</sub> – 1.5	.,
$V_{ICR}$	Input common-mode	voltage range	$V_{CC+} = 30 V^{(1)}$	Full range	0		V <sub>CC+</sub> – 2	V
01400				25°C	70	85		
CMRR	Common-mode rejec	tion ratio		Full range	60			dB
I <sub>source</sub>	Output source curren	t	V <sub>CC+</sub> = 15 V, V <sub>O</sub> = 2 V, V <sub>id</sub> = 1 V	25°C	20	40		mA
I <sub>SC</sub>	Short circuit to GND		V <sub>CC+</sub> = 15 V	25°C		40	60	mA
			V <sub>CC+</sub> = 15 V, V <sub>O</sub> = 2 V, V <sub>id</sub> = -1 V	2700	10	12		mA
I <sub>sink</sub>	Output sink current		$V_{CC+} = 15 \text{ V}, V_O = 0.2 \text{ V}, V_{id} = -1 \text{ V}$	25°C	12	50		μА
			V 00 V D 01 0	25°C	26	27		
			$V_{CC} = 30 \text{ V}, R_L = 2 \text{ k}\Omega$	Full range	26			.,
V <sub>OH</sub>	High-level output volt	age		25°C	27	28		V
			$V_{CC} = 30 \text{ V}, R_L = 10 \text{ k}\Omega$	Full range	27			
.,			B 4010	25°C		5	20	.,
$V_{OL}$	Low-level output volta	age	$R_L = 10 \text{ k}\Omega$	Full range			20	mV
SR	Slew rate at unity gai	n	$V_{CC+} = 15 \text{ V}, C_L = 100 \text{ pF}, R_L = 2 \text{ k}\Omega, V_I = 0.5 \text{ V to 3 V}, unity gain}$	25°C	0.2	0.4		V/μs
GBW	Gain bandwidth produ	uct	$V_{CC+} = 30 \text{ V}, V_I = 10 \text{ mV}, \\ C_L = 100 \text{ pF}, R_L = 2 \text{ k}\Omega, \\ f = 100 \text{ kHz}$	25°C	0.5	0.9		MHz
THD	Total harmonic distor	tion	$\begin{aligned} &V_{CC+} = 30 \text{ V},  V_{O} = 2  V_{pp}, \\ &C_{L} = 100 \text{ pF},  R_{L} = 2  k\Omega, \\ &f = 1 \text{ kHz},  A_{V} = 20 \text{ dB} \end{aligned}$	25°C		0.02		%
V <sub>n</sub>	Equivalent input noise	e voltage	$V_{CC} = 30 \text{ V}, R_S = 100 \Omega,$ f = 1 kHz	25°C		50		nV/√ <del>Hz</del>

<sup>(1)</sup> The input common-mode voltage of either input should not be allowed to go below -0.3 V. The upper end of the common-mode voltage range is  $V_{CC+}$  – 1.5 V, but either input can go to  $V_{CC+}$  + 0.3 V (but  $\leq$ 36 V) without damage.



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### Voltage Reference Electrical Characteristics

	PARAMETER		TEST CONDITIONS	T <sub>A</sub>	MIN	TYP	MAX	UNIT
		TL103W	L = 10 mA	25°C	2.482	2.5	2.518	
V <sub>REF</sub> Reference voltage	ILIUSW	$I_K = 10 \text{ mA}$	Full range	2.465		2.535	V	
	TI 402\\/	1 10 10	25°C	2.49	2.5	2.51	V	
		TL103WA	$I_K = 10 \text{ mA}$	Full range	2.48		2.52	
$\Delta V_{REF}$	Reference input volta over temperature ran		$V_{KA} = V_{REF}$ , $I_K = 10 \text{ mA}$	Full range		7	30	mV
I <sub>min</sub>	Minimum cathode cur regulation	rent for	$V_{KA} = V_{REF}$	25°C		0.5	1	mA
z <sub>ka</sub>	Dynamic impedance(	1)	$V_{KA} = V_{REF}$ , $\Delta I_K = 1$ mA to 100 mA, $f < 1$ kHz	25°C		0.2	0.5	Ω

(1) The dynamic impedance is defined as

$$|z_{ka}| = \frac{\Delta V_{KA}}{\Delta I_{K}}$$

# **Total Device Electrical Characteristics**

PARAMETER	TEST CONDITIONS	$T_{A}$	MIN	TYP	MAX	UNIT
	V <sub>CC+</sub> = 5 V, No load	Full range		0.7	1.2	m ^
excluding cathode-current reference	$V_{CC+} = 30 \text{ V}$ , No load	Full range			2	mA



### PACKAGE OPTION ADDENDUM

23-Apr-2007

### PACKAGING INFORMATION

Orderable Device	Status <sup>(1)</sup>	Package Type	Package Drawing	Pins	Package Qty	e Eco Plan <sup>(2)</sup>	Lead/Ball Finish	MSL Peak Temp <sup>(3)</sup>
TL103WAID	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TL103WAIDE4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TL103WAIDG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TL103WAIDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TL103WAIDRE4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TL103WAIDRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TL103WID	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TL103WIDE4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TL103WIDG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TL103WIDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TL103WIDRE4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TL103WIDRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM

<sup>(1)</sup> The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <a href="http://www.ti.com/productcontent">http://www.ti.com/productcontent</a> for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free** (RoHS): Ti's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

**Green (RoHS & no Sb/Br):** TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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# **PACKAGE OPTION ADDENDUM**

23-Apr-2007

In no event shall TI's liability arising out of such information excee to Customer on an annual basis.	ed the total purchase price of the TI part(s) at issue in this document sold by T

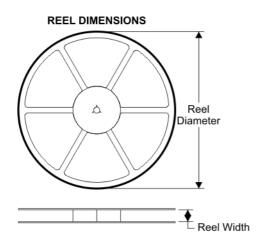


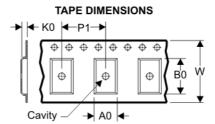
12-Jan-2008



RUMENTS

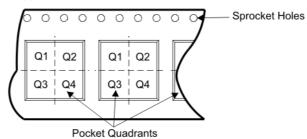
### TAPE AND REEL BOX INFORMATION





	Dimension designed to accommodate the component width
	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

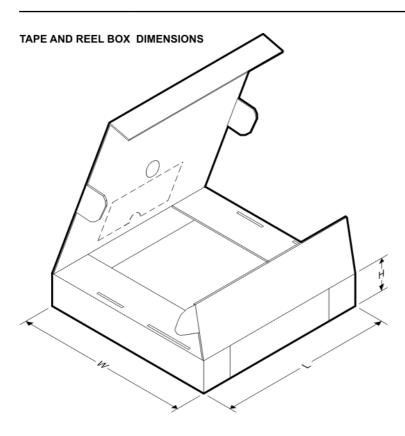


Device	Package	Pins	Site	Reel Diameter (mm)	Reel Width (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TL103WAIDR	D	8	SITE 27	330	12	6.4	5.2	2.1	8	12	Q1
TL103WIDR	D	8	SITE 27	330	12	6.4	5.2	2.1	8	12	Q1





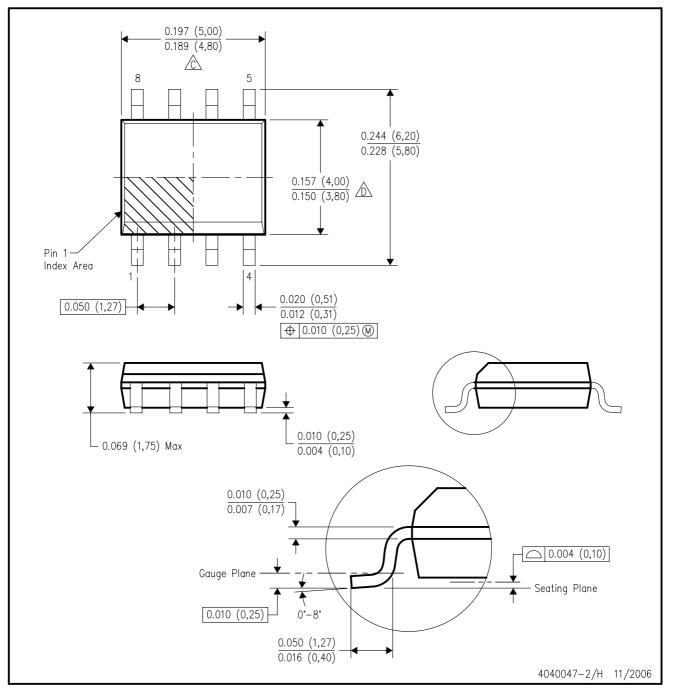
12-Jan-2008



Device	Package	Pins	Site	Length (mm)	Width (mm)	Height (mm)
TL103WAIDR	D	8	SITE 27	342.9	338.1	20.64
TL103WIDR	D	8	SITE 27	342.9	338.1	20.64

# D (R-PDSO-G8)

## PLASTIC SMALL-OUTLINE PACKAGE



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 (0,15) per end.
- Body width does not include interlead flash. Interlead flash shall not exceed .017 (0,43) per side.
- E. Reference JEDEC MS-012 variation AA.



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